NSN 5961-01-117-8262

Thyristor Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-117-8262 **Inclosure Material:** Metal **Overall Length:** 8.000 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Overall Width Across Flats:** 1.062 inches **Thread Size:** 0.500 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 200.0 reverse voltage, peak and 3.0 gate trigger voltage, dc **Current Rating Per Characteristic:** 40.00 amperes source cutoff current horsepower metric and 150.00 milliamperes forward current, total rms preset **Power Rating Per Characteristic:** 10.0 watts small-signal input power, common-collector blank **Special Features:** Junction pattern arrangement: pnpn **Thread Series Designator:** Unf **Terminal Type And Quantity:** 3 tab, solder lug Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: A110a0